NSN 5961-01-337-0056

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-337-0056 **Inclosure Material:** Glass **Overall Length:** Between 0.165 inches and 0.185 inches **Overall Height:** Between 0.070 inches and 0.076 inches **Overall Width:** Between 0.070 inches and 0.076 inches **Function For Which Designed:** Switching **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case and electrostatic sensitive **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 75.0 reverse voltage, dc **Current Rating Per Characteristic:** 500.00 milliamperes forward current, average absolute **Power Rating Per Characteristic:** 500.0 milliwatts small-signal input power, common-collector preset **Capacitance Rating In Picofarads:** 2.5 **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Precious Material And Location:** End caps surfaces silver **Precious Material:** Silver **Test Data Document:** 90536-7917020 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 case Shelf Life: N/a **Unit Of Measure: Demilitarization:**

Fiig: A110a0

No